

NP36P04SDG

-40V – -36A – P-channel Power MOS FET

R07DS1519EJ0100

Application : Automotive

Rev.1.00

Jun. 17, 2022

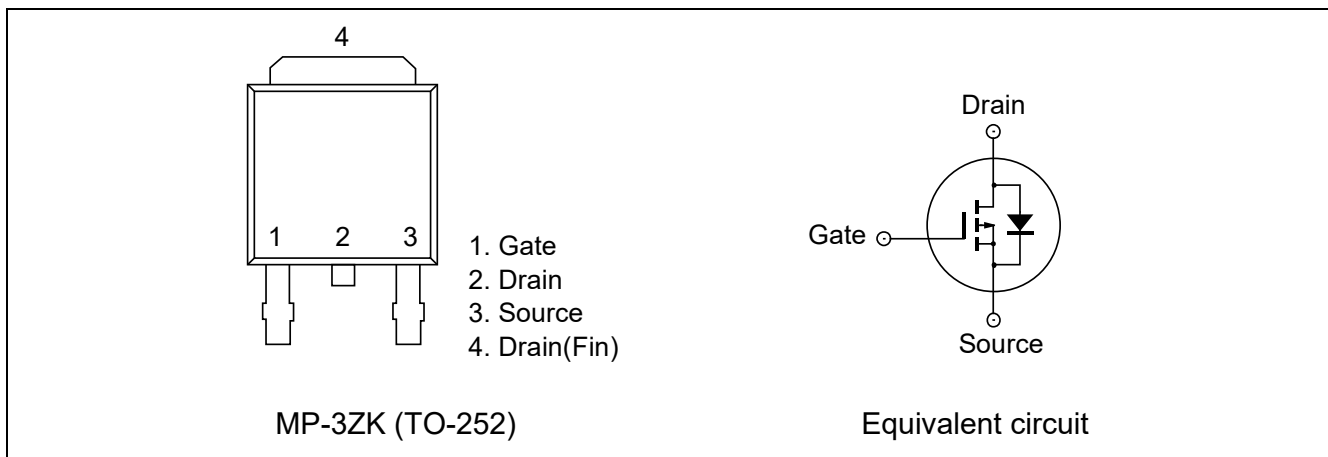
Description

This product is P-channel MOS Field Effect Transistor designed for high current switching applications.

Features

- Super low on-state resistance : $R_{DS(on)} = 17.0 \text{ m}\Omega \text{ Max. (} V_{GS} = -10 \text{ V, } I_D = -18 \text{ A)}$
 $R_{DS(on)} = 23.5 \text{ m}\Omega \text{ Max. (} V_{GS} = -4.5 \text{ V, } I_D = -18 \text{ A)}$
- Low input capacitance : $C_{iss} = 2800 \text{ pF Typ.}$
- Designed for automotive application and AEC-Q101 qualified.
- Pb-free (This product does not contain Pb in the external electrode)

Outline



Absolute Maximum Ratings

($T_a=25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Drain to Source Voltage ($V_{GS} = 0 \text{ V}$)	V_{DSS}	-40	V
Gate to Source Voltage ($V_{DS} = 0 \text{ V}$)	V_{GSS}	∓ 20	V
Drain Current (DC) ($T_c = 25^\circ\text{C}$)	$I_{D(DC)}$	∓ 36	A
Drain Current (pulse)	$I_{D(pulse)}$ ^{Notes1}	∓ 108	A
Total Power Dissipation ($T_c = 25^\circ\text{C}$)	P_{T1}	56	W
Total Power Dissipation ($T_a = 25^\circ\text{C}$)	P_{T2}	1.2	W
Channel Temperature	T_{ch}	175	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to 175	$^\circ\text{C}$
Single Avalanche Current	I_{AS} ^{Notes2}	26	A
Single Avalanche Energy	E_{AS} ^{Notes2}	67	mJ

Notes 1. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

2. Starting $T_{ch}=25^\circ\text{C}$, $V_{DD} = -20\text{V}$, $R_G = 25 \Omega$, $V_{GS} = -20 \rightarrow 0\text{V}$, $L = 100\mu\text{H}$

Thermal Resistance

Channel to Case Thermal Resistance	$R_{th(ch-c)}$ ^{Notes3}	2.68	°C/W
Channel to Ambient Thermal Resistance	$R_{th(ch-a)}$ ^{Notes3}	125	°C/W

Electrical Characteristics

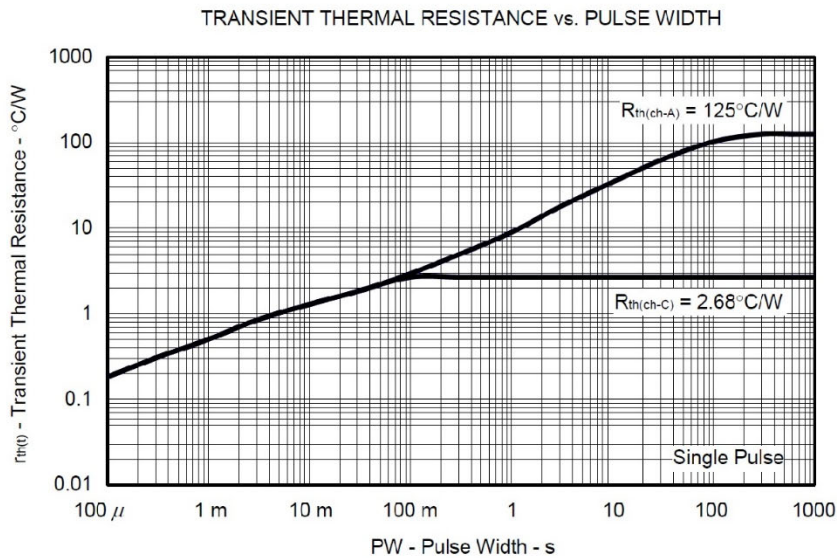
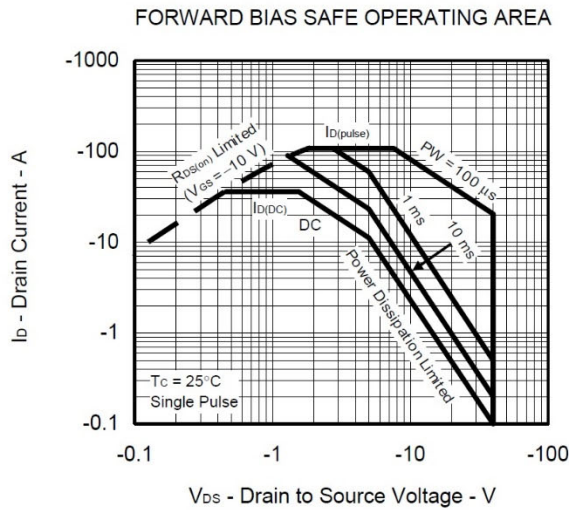
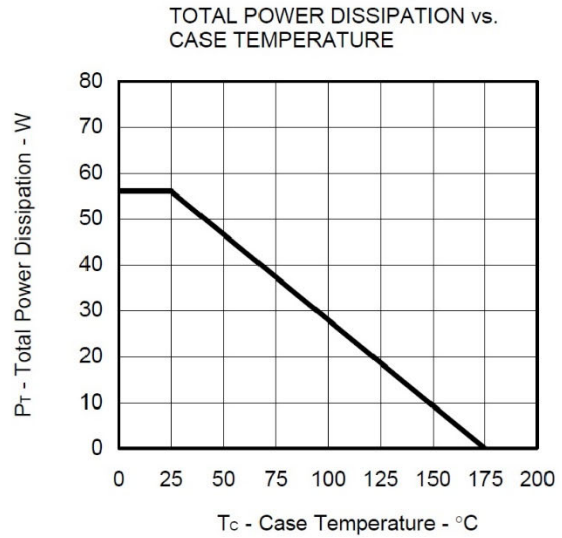
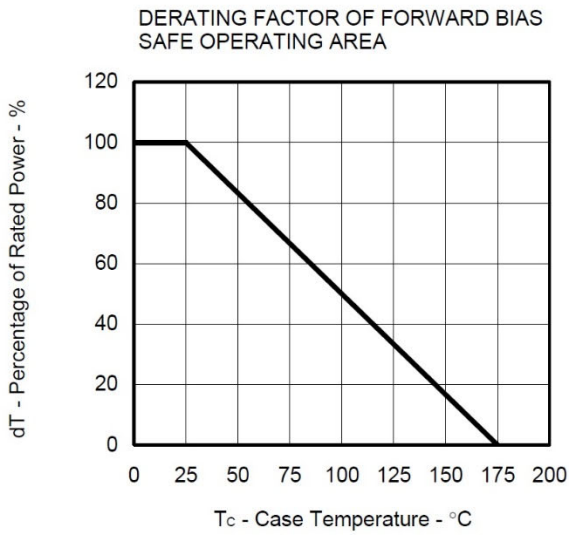
(T_a=25°C)

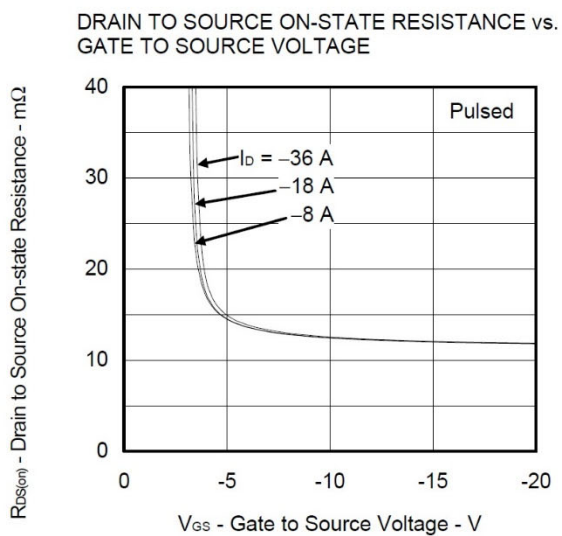
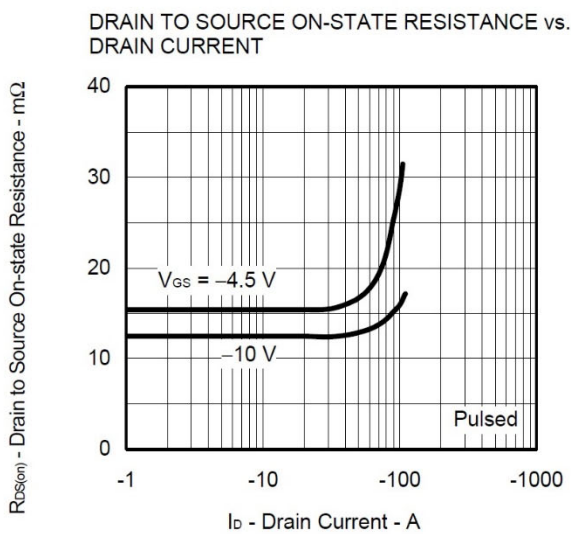
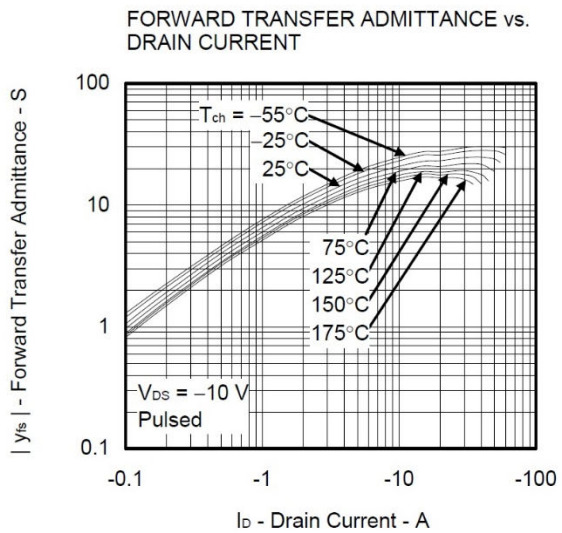
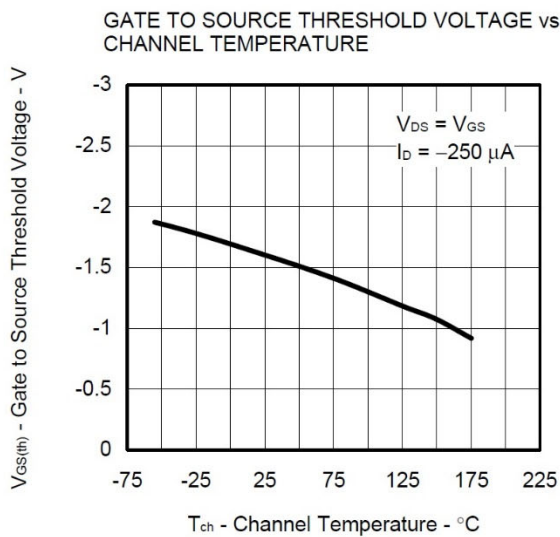
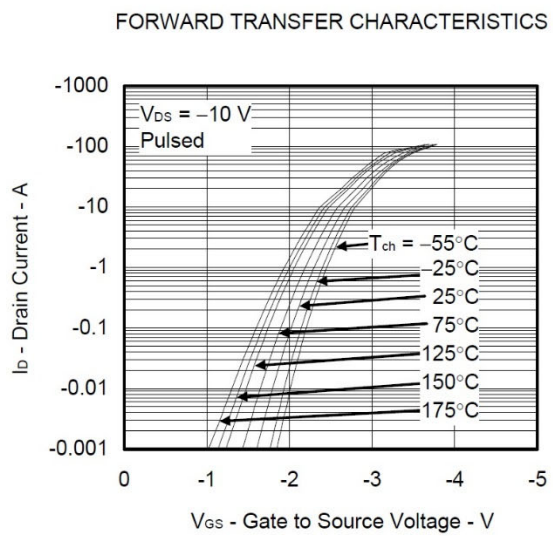
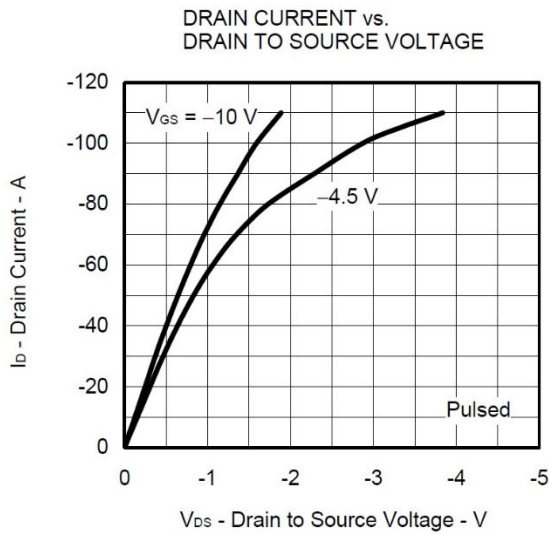
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero Gate Voltage Drain Current	I_{DSS}	—	—	-10	μA	V _{DS} = -40 V, V _{GS} = 0 V
Gate Leakage Current	I_{GSS}	—	—	±100	nA	V _{GS} = ±20 V, V _{DS} = 0 V
Gate to Source Threshold Voltage	V _{GS(th)}	-1.0	-1.6	-2.5	V	V _{DS} = V _{GS} , I _D = -250 μA
Forward Transfer Admittance	y _{fs} ^{Notes4}	12	23	—	S	V _{DS} = -10 V, I _D = -18 A
Drain to Source On-state Resistance	$R_{DS(on)1}$ ^{Notes4}	—	12.5	17.0	mΩ	V _{GS} = -10 V, I _D = -18 A
	$R_{DS(on)2}$ ^{Notes4}	—	15.4	23.5	mΩ	V _{GS} = -4.5 V, I _D = -18 A
Input Capacitance	C _{iss}	—	2800	—	pF	V _{DS} = -10 V
Output Capacitance	C _{oss}	—	450	—	pF	V _{GS} = 0 V
Reverse Transfer Capacitance	C _{rss}	—	280	—	pF	f = 1 MHz
Turn-on Delay Time	t _{d(on)}	—	8	—	ns	V _{DD} = -20 V
Rise Time	t _r	—	10	—	ns	I _D = -18 A
Turn-off Delay Time	t _{d(off)}	—	250	—	ns	V _{GS} = -10 V
Fall Time	t _f	—	140	—	ns	R _G = 0 Ω
Total Gate Charge	Q _g	—	55	—	nC	V _{DD} = -32 V
Gate to Source Charge	Q _{gs}	—	7	—	nC	V _{GS} = -10 V
Gate to Drain Charge	Q _{gd}	—	15	—	nC	I _D = -36 A
Body Diode Forward Voltage	V _{F(S-D)} ^{Notes4}	—	0.95	1.5	V	I _F = -36 A, V _{GS} = 0 V
Reverse Recovery Time	t _{rr}	—	44	—	ns	I _F = -36 A, V _{GS} = 0 V
Reverse Recovery Charge	Q _{rr}	—	51	—	nC	di/dt = -100 A/μs

Notes 3. Designed target value on Renesas measurement condition. Not subject to production test.

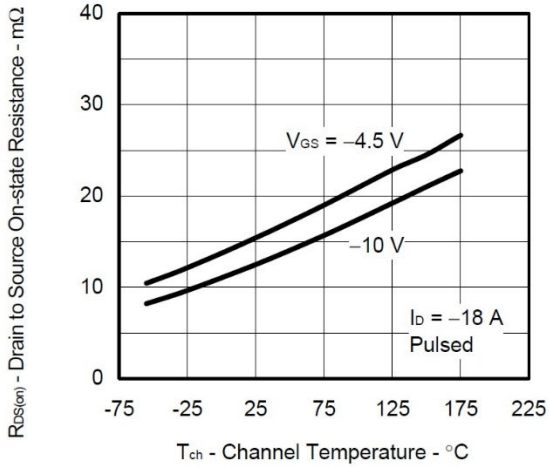
4. Pulse test.

Typical Characteristics

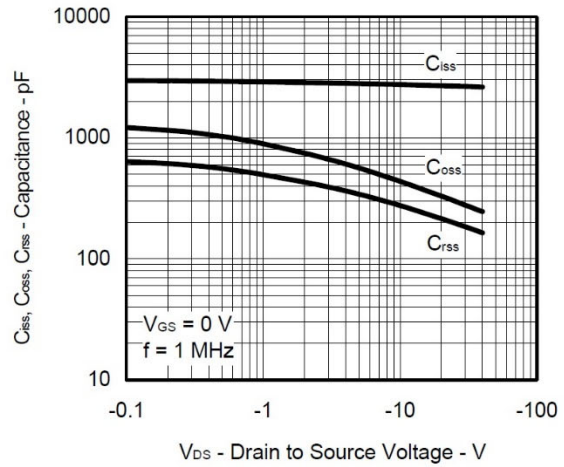




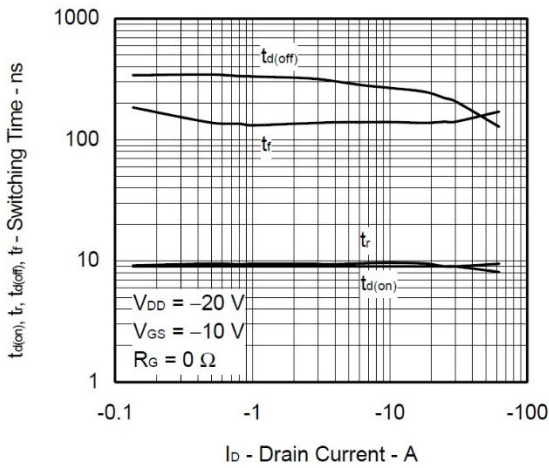
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



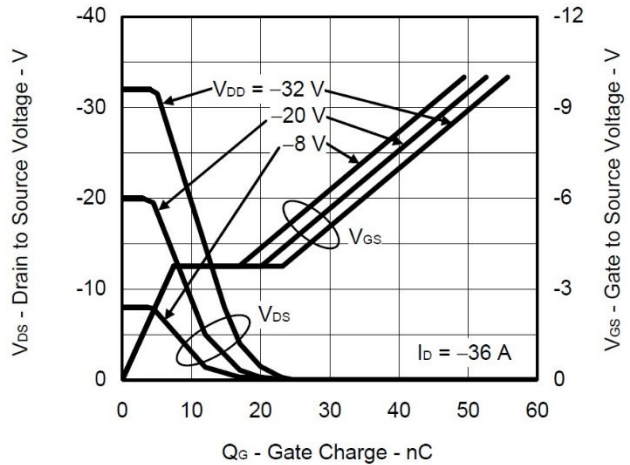
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



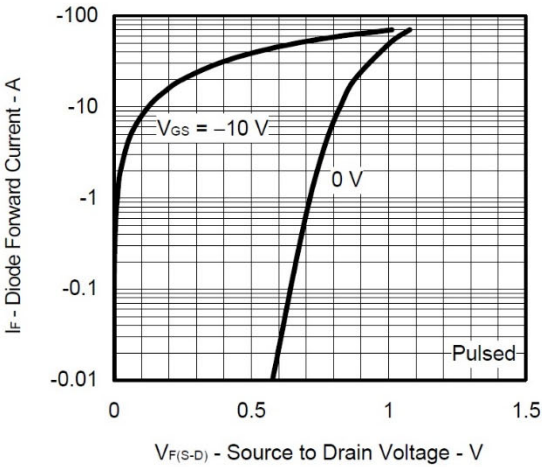
SWITCHING CHARACTERISTICS



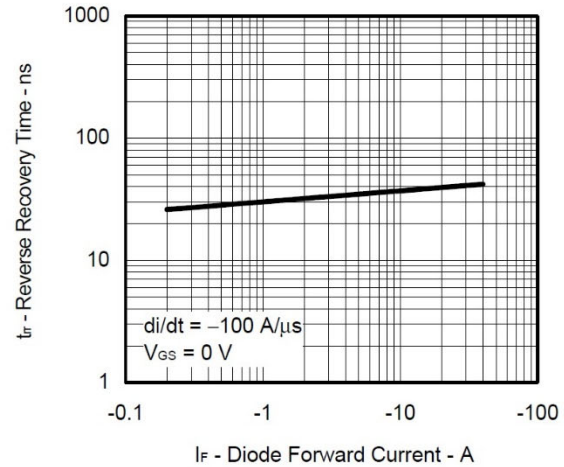
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



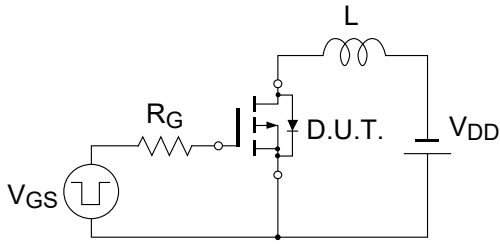
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



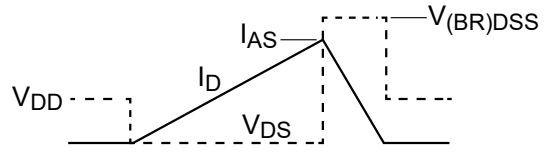
Test Circuit

Avalanche

Test Circuit



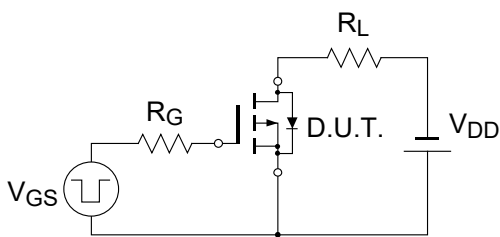
Waveform



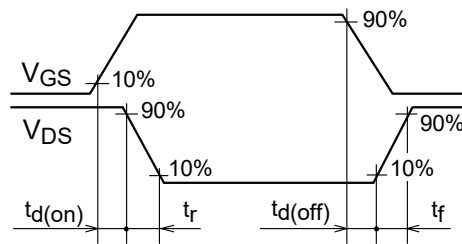
$$E_{AS} = \frac{1}{2} \cdot L \cdot I_{AS}^2 \cdot \frac{V_{(BR)DSS}}{V_{(BR)DSS} - V_{DD}}$$

Switching Time

Test Circuit

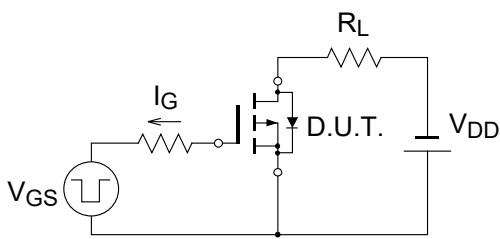


Waveform

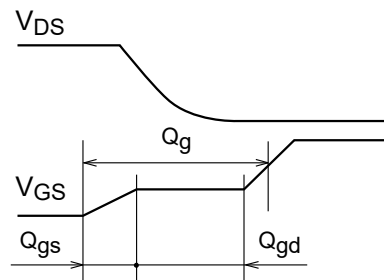


Gate Charge

Test Circuit

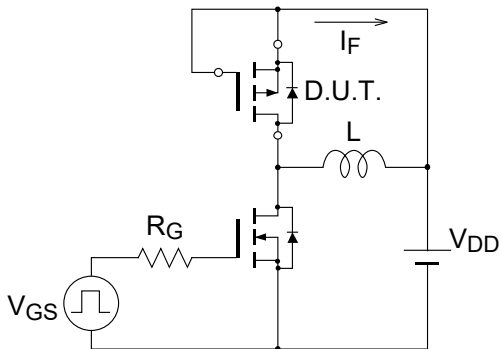


Waveform

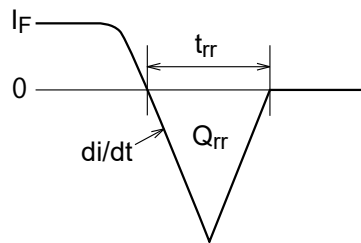


Reverse Recovery

Test Circuit



Waveform



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